

Supplementary information

Residual polymer stabiliser causes anisotropic conductivity in metal nanoparticle 2D and 3D printed electronics

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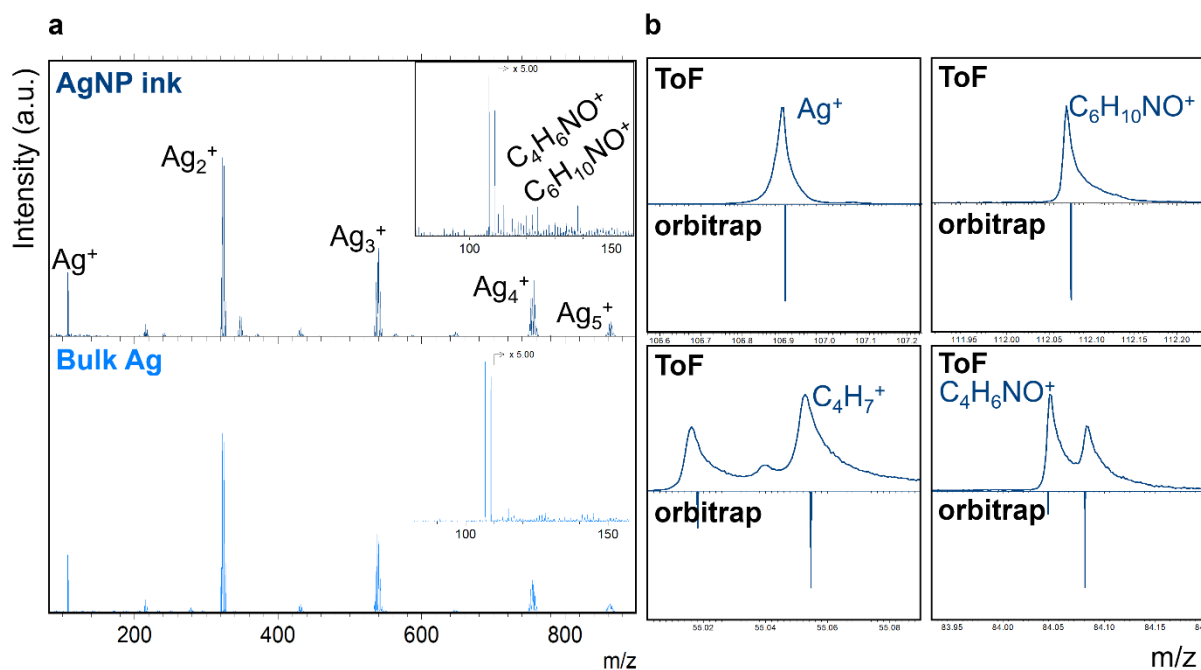


Fig. S1 Unambiguous identification of PVP in inkjet-printed AgNPs (arbitrary intensities). **a** Measured spectra for AgNP (top) and reference bulk Ag (bottom). The inserts show a zoomed-in view with characteristic PVP peaks indicated. **b** High resolution view of peaks of main secondary ions of interest. The top curves show the ToF-SIMS signal and the bottom curves show the orbitSIMS. The orbitrap data confirms that there is no interference within the ToF peaks of interest.

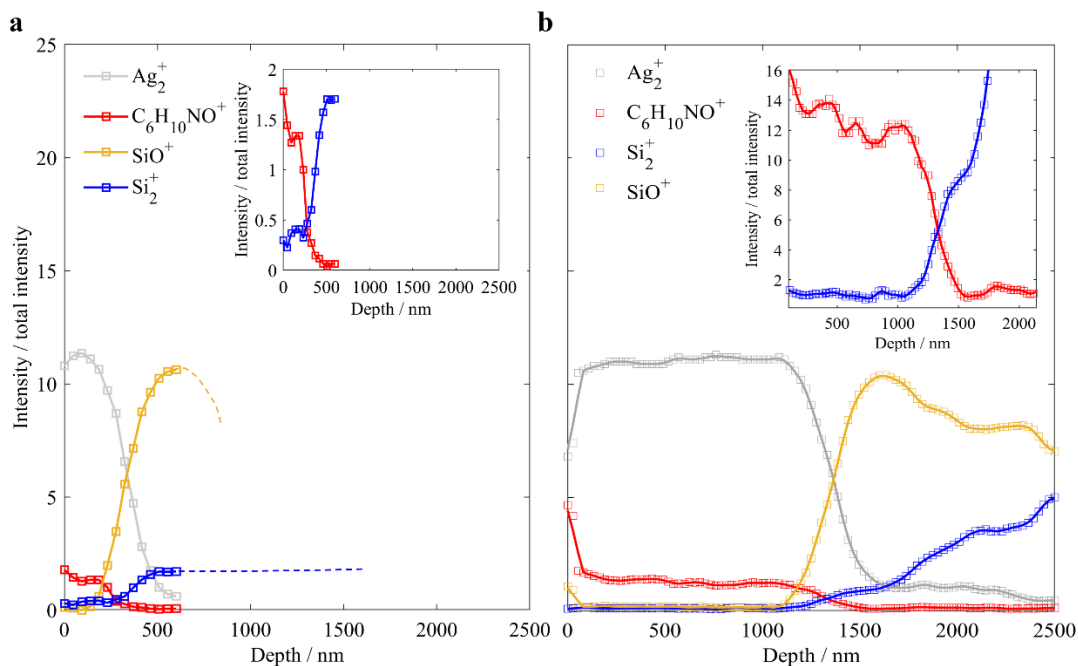


Fig. S2 ToF-SIMS depth profiles of **a** 1 printed layer and **b** 4 printed layers of AgNP samples.

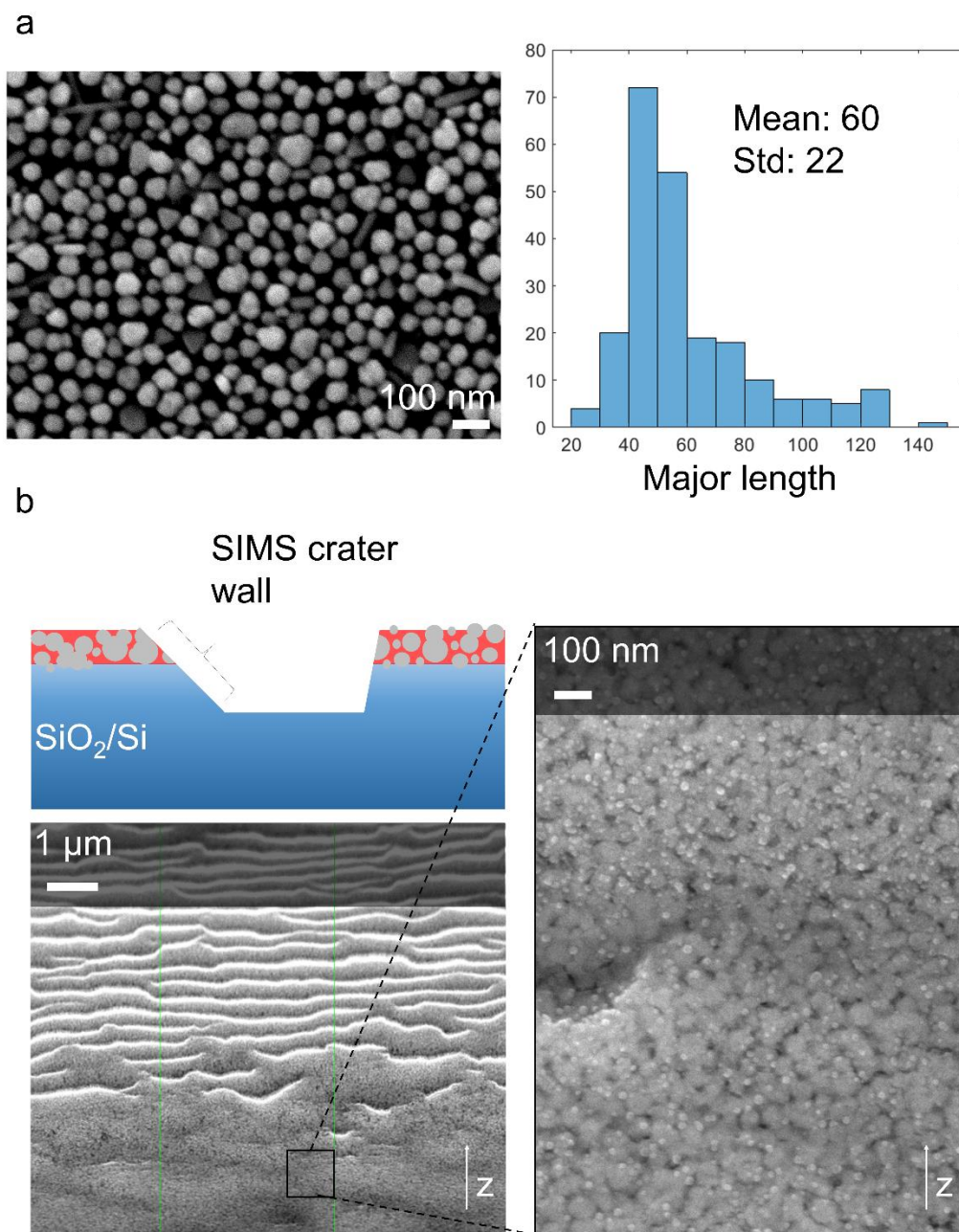


Fig. S3 a Electron micrograph and AgNPs size distribution of the silver ink. **b** Electron micrograph of the ToF-SIMS crater wall after depth profiling.

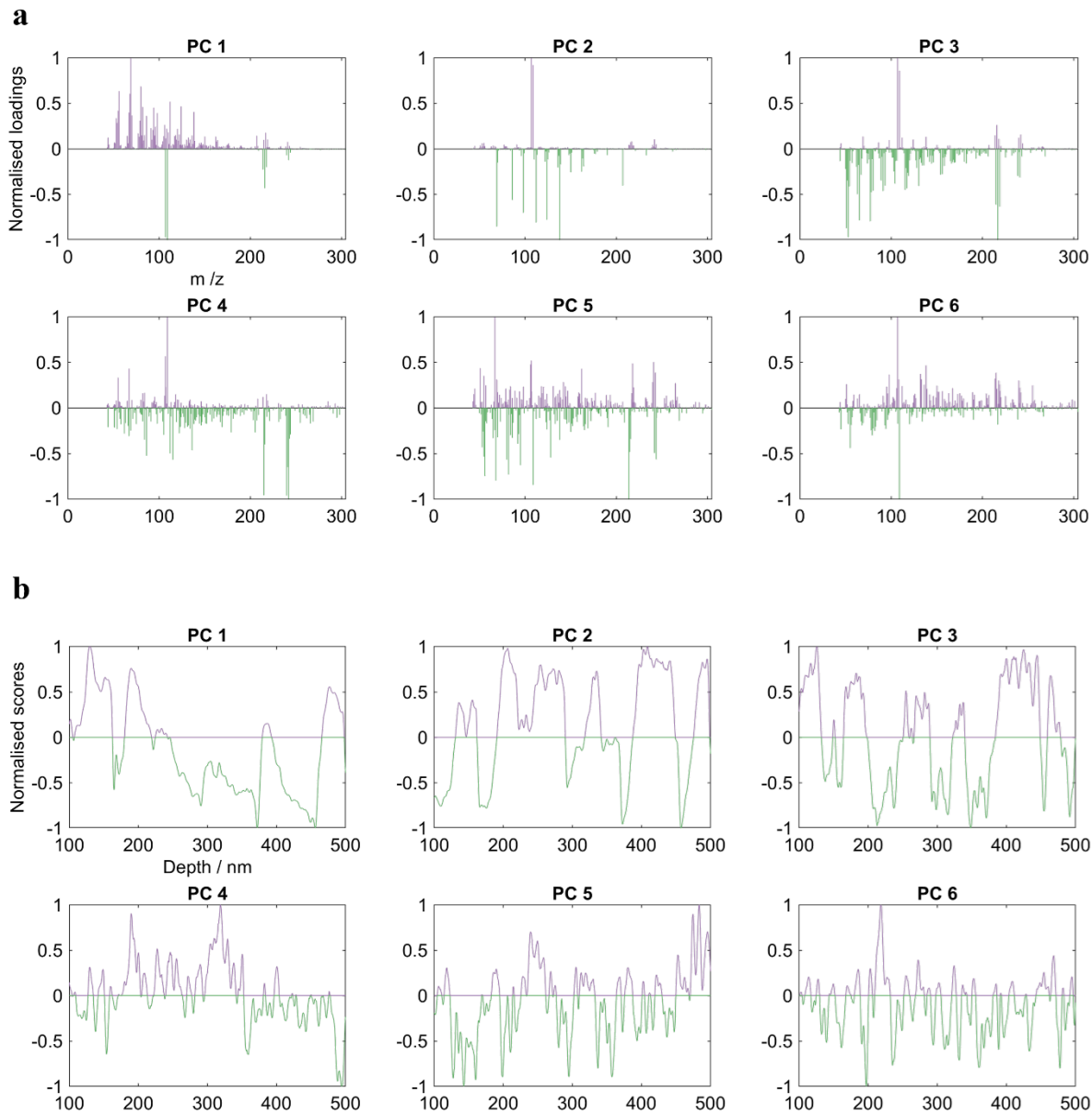


Fig. S4 Principal component analysis results of the ToF-SIMS depth profiling data within a single printed layer of the AgNPs ink. Depth levels are used as observations and secondary ion mass peaks are used as variables. **a** Loadings. **b** Scores

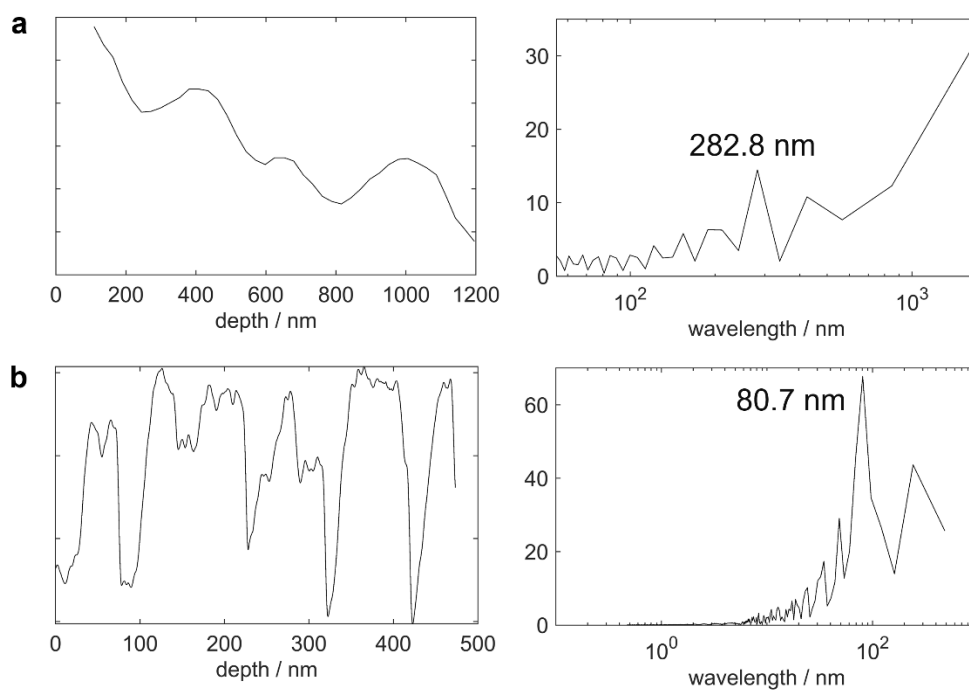


Fig. S5: Estimation of period of repeating patterns by Fast Fourier transforms of the ToF-SIMS depth profiling data within **a** 4 printed layers and **b** 1 printed layer (with higher depth resolution).

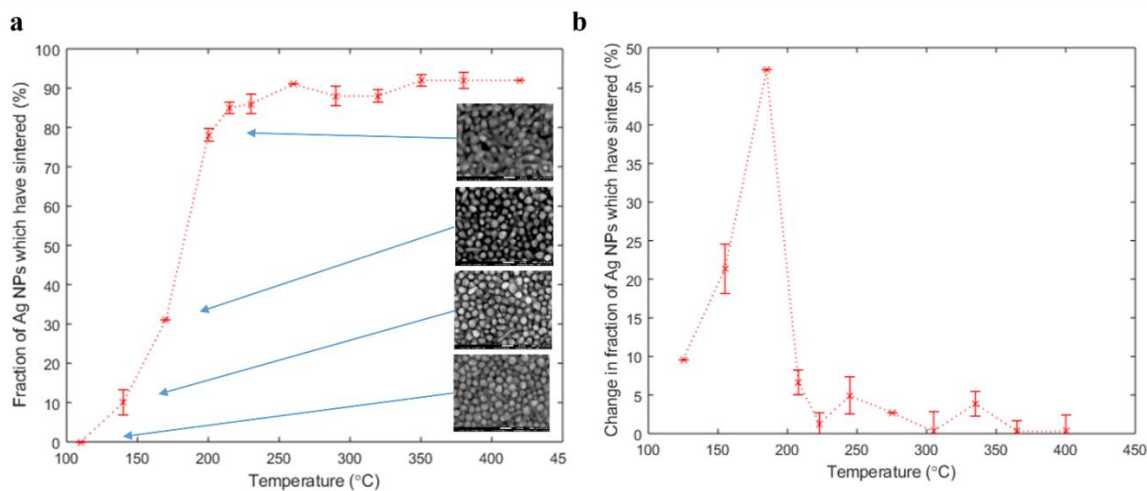


Fig. S6: **a** fraction of Ag NPs which have sintered against temperature. Exemplary images are included with arrow indications to the correspond data points. Error bars indicate standard deviation. **b** Change in fraction of Ag NPs which have sintered with increasing temperature. Error bars indicate standard deviation.

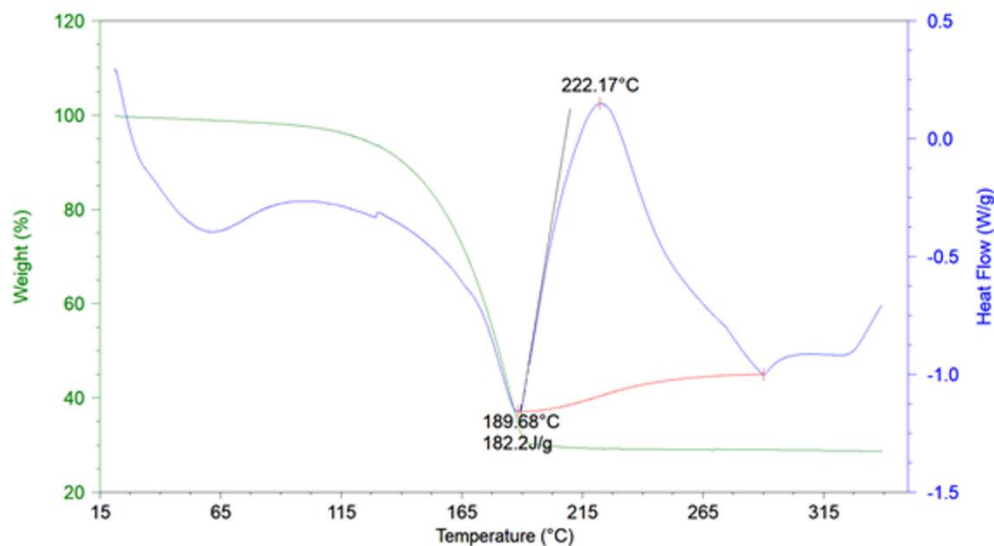


Fig. S7 Simultaneous DSC/TGA measurements of the AgNP ink. Data reveal weight loss of approximately 70% by $T = 190^{\circ}\text{C}$. We attribute this to the evaporation of the solvent present in the ink. The DSC measurement shows an exothermic peak believed to be the result of NP sintering up to $T = 290^{\circ}\text{C}$.

Table ST1: XPS peak fitting for C1s spectra of printed AgNPs sintered at different temperatures and corresponding estimated compositions.

	GROUP	POSITIO N(EV)	FWHM (EV)	AREA	CORREC TED AREA	ATOMIC CONC (%)
RT	C-C	284.82	1.39	1687.44	2143.31	58.3
	N-C=O	287.6	1.39	271.477	344.859	9.38
	C-N	286.38	1.39	542.954	689.681	18.76
	C-O	289.28	1.39	109.143	498.759	13.57
100°C	C-C	284.78	1.27	1459.87	1854.25	63.13
	N-C=O	287.42	1.27	172.05	218.552	7.44
	C-N	286.2	1.27	344.1	437.082	14.88
	C-O	288.89	1.27	93.506	427.291	14.55
150°C	C-C	284.8	1.31	1805.19	2292.9	73.89
	N-C=O	287.59	1.31	166.357	211.327	6.81
	C-N	286.24	1.31	332.713	422.629	13.62

230°C	C-O	289.01	1.31	38.5496	176.163	5.68
	C-C	284.85	1.32	1345.51	1709.03	66.05
	N-C=O	287.66	1.32	138.667	176.151	6.81
	C-N	286.3	1.32	277.334	352.282	13.62
	C-O	289.21	1.32	76.5669	349.895	13.52

Table ST2: XPS peak fitting for N1s spectra of printed AgNPs sintered at different temperatures and corresponding estimated compositions.

		POSITION (EV)	FWHM (EV)	AREA	CORRECTED AREA	ATOMIC CONC (%)
RT SURFACE	C-N-Ag	397.83	1.25	114.064	294.412	63.82
	C-N	399.79	1.61	64.7248	166.897	36.18
RT BULK	C-N-Ag	398.8	1	1.00E-20	2.58E-20	0
	C-N	400.69	1.21	33.7063	86.8754	100
100 °C SURFACE	C-N-Ag	399	1.54	133.438	344.199	71.42
	C-N	400.8	1.7	53.4481	137.745	28.58
100 °C BULK	C-N-Ag	398.01	1.7	57.7153	148.94	34.82
	C-N	399.88	1.7	108.148	278.827	65.18
150 °C SURFACE	C-N-Ag	398.04	1.7	164.003	423.311	65.79
	C-N	400.51	1.7	85.3673	220.082	34.21
150 °C BULK	C-N-Ag	398.09	1.7	98.3761	253.907	58.06
	C-N	400.74	1.26	71.1677	183.447	41.94
230 °C SURFACE	C-N-Ag	398.21	1.43	83.444	215.389	40.7
	C-N	400.54	1.7	121.726	313.849	59.3
230 °C BULK	C-N-Ag	398.23	1.7	29.3323	75.7025	23.68
	C-N	400.57	1.38	94.6347	243.961	76.32